MOSFETs Silicon N-channel MOS (U-MOSIX-H)

TPN4R806PL

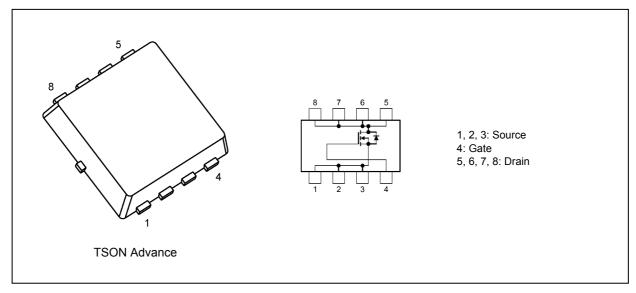
1. Applications

- DC-DC Converters
- Switching Voltage Regulators
- Motor Drivers

2. Features

- (1) High-speed switching
- (2) Small gate charge: $Q_{SW} = 9.5 \text{ nC}$ (typ.)
- (3) Small output charge: $Q_{oss} = 24 \text{ nC}$ (typ.)
- (4) Low drain-source on-resistance: $R_{DS(ON)} = 3.5 \text{ m}\Omega \text{ (typ.)} (V_{GS} = 10 \text{ V})$
- (5) Low leakage current: $I_{DSS} = 10 \ \mu A \ (max) \ (V_{DS} = 60 \ V)$
- (6) Enhancement mode: V_{th} = 1.5 to 2.5 V (V_{DS} = 10 V, I_D = 0.3 mA)

3. Packaging and Internal Circuit



4. Absolute Maximum Ratings (Note) (T_a = 25 °C unless otherwise specified)

Characterist	tics		Symbol	Rating	Unit
Drain-source voltage			V _{DSS}	60	V
Gate-source voltage			V _{GSS}	±20]
Drain current (DC)	(T _c = 25 °C)	(Note 1)	Ι _D	72	A
Drain current (DC)	(Silicon limit)	(Note 1), (Note 2)		105]
Drain current (pulsed)	(t = 100 μs)	(Note 1)	I _{DP}	200	
Power dissipation	(T _c = 25 °C)		PD	104	W
Power dissipation		(Note 3)		2.67]
Power dissipation		(Note 4)		0.63	
Single-pulse avalanche energy		(Note 5)	E _{AS}	28	mJ
Single-pulse avalanche current		(Note 5)	I _{AS}	72	A
Channel temperature			T _{ch}	175	°C
Storage temperature			T _{stg}	-55 to 175	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

5. Thermal Characteristics

Characteristics			Symbol	Max	Unit
Channel-to-case thermal resistance	(T _c = 25 °C)		R _{th(ch-c)}	1.43	°C/W
Channel-to-ambient thermal resistance	(T _a = 25 °C)	(Note 3)	R _{th(ch-a)}	56	
Channel-to-ambient thermal resistance	(T _a = 25 °C)	(Note 4)	R _{th(ch-a)}	235	

Note 1: Ensure that the channel temperature does not exceed 175 °C.

Note 2: Limited by silicon chip capability.

Note 3: Device mounted on a glass-epoxy board (a), Figure 5.1

Note 4: Device mounted on a glass-epoxy board (b), Figure 5.2

Note 5: V_DD = 48 V, T_ch = 25 °C (initial), L = 4.3 $\mu H, \, I_{AS}$ = 72 A

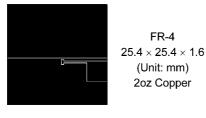
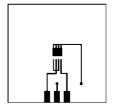


Fig. 5.1 Device Mounted on a Glass-Epoxy Board (a)



FR-4 25.4 × 25.4 × 1.6 (Unit: mm) 2oz Copper

Fig. 5.2 Device Mounted on a Glass-Epoxy Board (b)

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

6. Electrical Characteristics

6.1. Static Characteristics (T_a = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I _{GSS}	V_{GS} = ±20 V, V_{DS} = 0 V	_	_	±0.1	μA
Drain cut-off current	I _{DSS}	V _{DS} = 60 V, V _{GS} = 0 V			10	
Drain-source breakdown voltage	V _{(BR)DSS}	I _D = 10 mA, V _{GS} = 0 V	60	—	—	V
Drain-source breakdown voltage (Note 6)	V _{(BR)DSX}	I _D = 10 mA, V _{GS} = -20 V	45	_	_	
Gate threshold voltage	V _{th}	V _{DS} = 10 V, I _D = 0.3 mA	1.5		2.5	
Drain-source on-resistance	R _{DS(ON)}	V _{GS} = 4.5 V, I _D = 12 A		6.2	9.1	mΩ
		V _{GS} = 10 V, I _D = 36 A	_	3.5	4.8	

Note 6: If a reverse bias is applied between gate and source, this device enters V_{(BR)DSX} mode. Note that the drainsource breakdown voltage is lowered in this mode.

6.2. Dynamic Characteristics ($T_a = 25$ °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	C _{iss}	V _{DS} = 30 V, V _{GS} = 0 V, f = 1 MHz	_	2130	2770	pF
Reverse transfer capacitance	C _{rss}		—	45	90	
Output capacitance	C _{oss}		_	360	—	
Gate resistance	r _g	—	_	0.8	1.3	Ω
Switching time (rise time)	tr	See Fig. 6.2.1	_	4.0	—	ns
Switching time (turn-on time)	t _{on}		_	15	_	
Switching time (fall time)	t _f		_	5.1	_	
Switching time (turn-off time)	t _{off}		_	27	_	

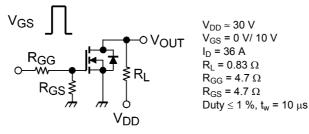


Fig. 6.2.1 Switching Time Test Circuit

6.3. Gate Charge Characteristics ($T_a = 25$ °C unless otherwise specified)

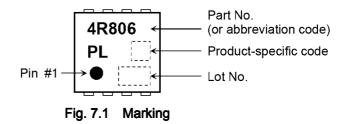
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Total gate charge (gate-source plus	Qg	$V_{DD} \approx 30$ V, V_{GS} = 10 V, I_D = 36 A	_	29	_	nC
gate-drain)		$V_{DD} \approx 30$ V, V_{GS} = 4.5 V, I_D = 36 A	_	14	_	
Gate-source charge 1	Q _{gs1}	$V_{DD} \approx 30$ V, V_{GS} = 10 V, I_D = 36 A	_	8.0	_	
Gate-drain charge	Q _{gd}		_	5.5	_	
Gate switch charge	Q _{SW}		_	9.5	—	
Output charge	Q _{oss}	V _{DS} = 30 V, V _{GS} = 0 V, f = 1 MHz	_	24	_	

6.4. Source-Drain Characteristics ($T_a = 25$ °C unless otherwise specified)

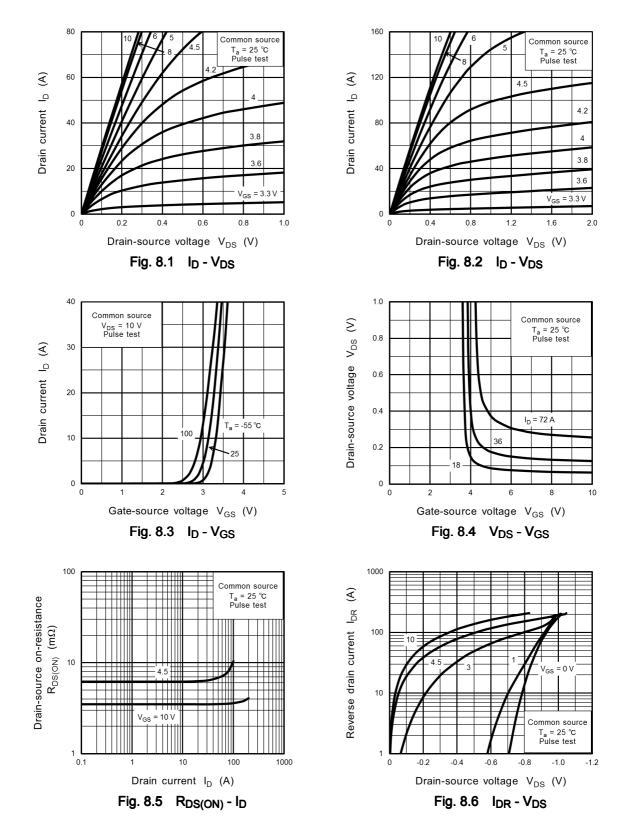
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Reverse drain current (pulsed) (Note 7	I _{DRP} (t = 100 μs)	—	—	—	200	A
Diode forward voltage	V _{DSF}	I _{DR} = 72 A, V _{GS} = 0 V	_	_	-1.2	V
Reverse recovery time	t _{rr}	I _{DR} = 18 A, V _{GS} = 0 V,	_	31	_	ns
Reverse recovery charge	Q _{rr}	-dI _{DR} /dt = 100 A/μs		26	_	nC

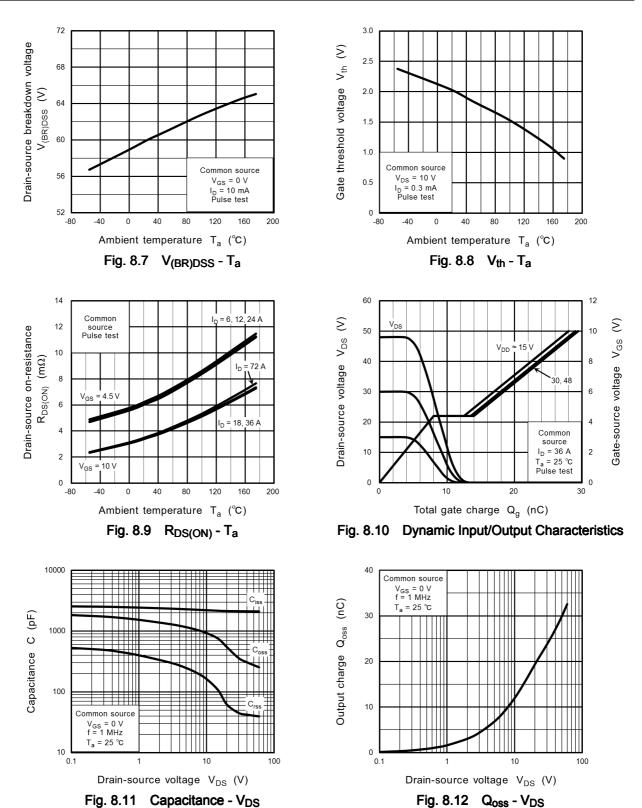
Note 7: Ensure that the channel temperature does not exceed 175 $^\circ \! \text{C}.$

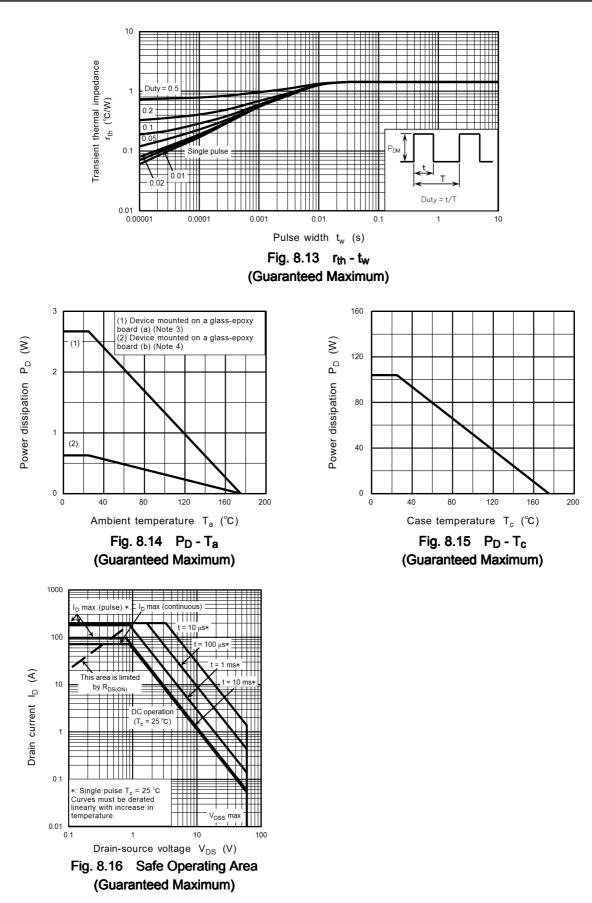
7. Marking



8. Characteristics Curves (Note)







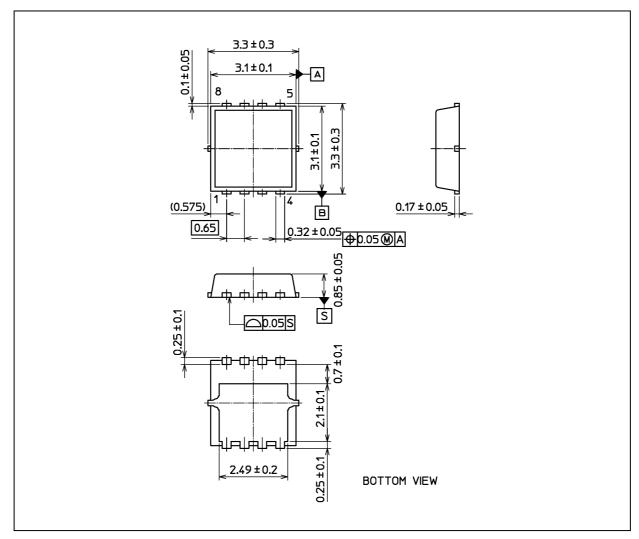
Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



TPN4R806PL

Package Dimensions

Unit: mm



Weight: 0.02 g (typ.)

Package Name(s)
TOSHIBA: 2-3X1S
Nickname: TSON Advance

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Телефон: 8 (812) 309 58 32 (многоканальный) **Факс:** 8 (812) 320-02-42 **Электронная почта:** <u>org@eplast1.ru</u> **Адрес:** 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.